

isc N-Channel MOSFET Transistor

DMN10H100SK3

FEATURES

- Drain Current $-I_D = 18A @ T_C = 25^\circ C$
- Drain Source Voltage-
: $V_{DS} = 100V(\text{Min})$
- Static Drain-Source On-Resistance
: $R_{DS(on)} = 80m\Omega (\text{Max})$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

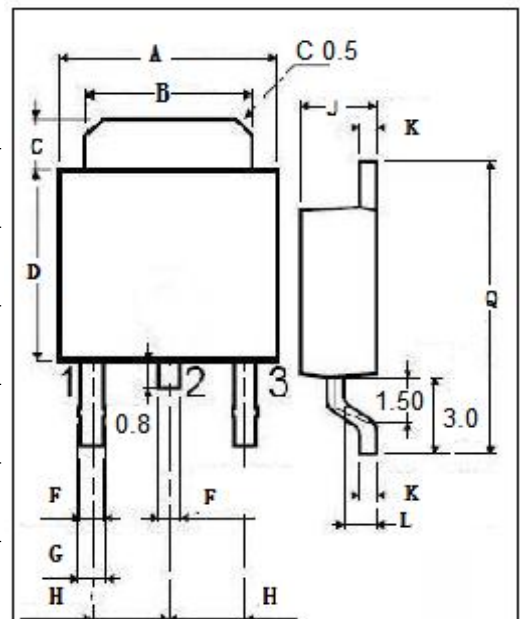
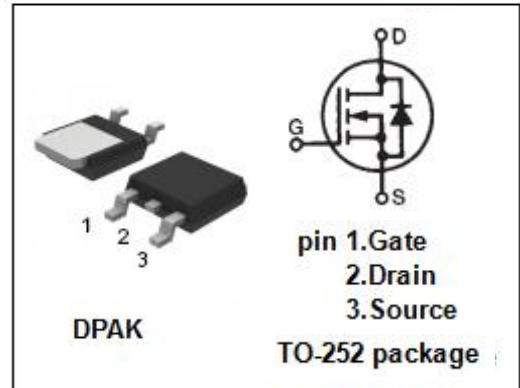
- Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	100	V
V_{GS}	Gate-Source Voltage-Continuous	± 20	V
I_D	Drain Current-Continuous	18	A
I_{DM}	Drain Current-Single Pluse	16	A
P_D	Total Dissipation @ $T_C = 25^\circ C$	37	W
T_J	Max. Operating Junction Temperature	-55~150	$^\circ C$
T_{stg}	Storage Temperature	-55~150	$^\circ C$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th j-c}$	Thermal Resistance, Junction to Case	3.3	$^\circ C/W$



DIM	mm	
	MIN	MAX
A	6.40	6.60
B	5.20	5.40
C	1.15	1.35
D	5.70	6.10
E	0.65	
F	0.75	
G	2.10	2.50
H	2.10	2.40
I	0.40	0.60
J	0.90	1.10
K	9.90	10.1
L	0.40	0.60
M	0.90	1.10
N	0.40	0.60
O	0.90	1.10
P	0.40	0.60
Q	0.90	1.10

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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	100		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 0.25mA	1.0	3.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 3.3A		80	mΩ
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V; V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 80V; V _{GS} = 0		1.0	μA
V _{SD}	Forward On-Voltage	I _S = 3.2A; V _{GS} = 0		1.0	V

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